AMENDMENT TO THE CLAIMS:

- 1. (Currently Amended) A reflective type liquid crystal display device on which display is created by reflecting light incident from the display observation side, comprising:
- a display electrode made of a reflective material for reflecting the incident light on a surface thereof;
- a back-surface electrode disposed in contact with a back surface of the display electrode, and
- a transistor for controlling current to the display electrode, said back-surface electrode and the transistor being electrically interconnected,

wherein said transistor is a thin-film transistor which has an active layer, and a portion of the back-surface electrode is directly connected to said active layer via a contact hole,

wherein said display electrod: and said back-surface electrode are patterned into the same shape, and

- a thickness of said back-surface electrode is such that no substantial protrusion is formed in said display electrode.
 - 2. (Original) The device according to claim 1, wherein said back-surface electrode is made of a high melting point metal.
 - 3. (Original) The device according to claim 2, wherein said display electrode is made of aluminum.
 - 4. (Canceled)
 - 5. (Canceled)
- 6. (Currently Amended) The device according to claim ± 1 , wherein said active layer is a polycrystalline silicon layer.
 - 7. (Original) The device according to claim 6, wherein said back-surface electrode is made of a high melting point metal.
- 8. (Currently Amended) The method of manufacturing a reflective type liquid crystal display device on which display is created by reflecting light incident from the display observation side, comprising:
- a step of forming a back-surface electrode layer, a thickness of said back-surface electrode layer is such that no substantial protrusion is formed in said display electrode;
- a step of forming a display electrode layer constituted of a reflective material on the back-surface electrode layer; and
- a step of patterning the forme 1 back-surface electrode layer and the display electrode layer to form a surface electrode and a back-surface electrode in the same shape,

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to form a display electrode for reflecting the incident light by a surface thereof and the back-surface electrode disp sed in contact with a back surface of the display electrode.

- 9. (Original) The method according to claim 8, further comprising:
- a process of forming a thin film transistor as an active layer of polycrystalline silicon on a substrate;
 - a step of forming an insulating film to cover the thin film transistor; and
 - a step of forming a contact hale in the insulating film, wherein
- said back-surface electrode is formed on a smoothened film with said contact hole formed therein.
- 10. (Currently Amended) The method of manufacturing a reflective type liquid crystal display device on which display is created by reflecting light incident from the display observation side comprising:
 - a step of forming a back-surface electrode layer;
- a step of forming a display electrode layer constituted of a reflective material on the back-surface electrode layer.
- a step of patterning the formed back-surface electrode layer and the display electrode layer to form a surface electrode and a back-surface electrode in the same shape:
- to form a display electrode for reflecting the incident light by a surface thereof and the back-surface electrode disposed in contact with a back surface of the display electrode:
- a process of forming a thin film transistor as an active layer of polycrystalline silicon on a substrate:
 - a step of forming an insulating film to cover the thin film transistor; and
 - a step of forming a contact he le in the insulating film, wherein
- said back-surface electrode is formed on a smoothened film with said contact hole formed therein The method of according to eaim 9, wherein
 - seid back-surface electrode is made of a high melting point metal.
 - 11. (Original) The method according to claim 10, wherein
- said high melting point metal is selected from the group consisting of molybdenum, titanium, tungsten, tantalum and chromium, or an alloy thereof.
- 12. (Previously Added) The cevice according to claim 1, wherein a part of the back-surface electrode elongates to a place above a part of the active layer and the contact hole is formed between the one end portion of the back-surface electrode and the part of the active layer.



- 13. (New) A reflective type liquid crystal display device comprising:
- a back-surface electrode layer;
- a display electrode layer is constituted of a reflective material on the back-surface electrode layer;
- a back-surface electrode layer and the display electrode layer are patterened to form a surface electrode and a back-surface electrode in the same shape;
- a display electrode for reflecting the incident light by a surface thereof and the backsurface electrode disposed in contact with a back surface of the display electrode;
- a thin film transistor is forme i as an active layer of polycrystalline silicon on a substrate:
 - an insulating layer is formed to cover the thin film transistor; and
 - a contact hole is formed in the insulating film, wherein
- said back-surface electrode is formed on a smoothened film with said contact hole formed therein, wherein
 - said back-surface electrode is made of a high melting point metal.
- 14. (New) The device according to claim 1, wherein the back-surface electrode is made of a non-oxide metal.
 - 15. (New) The device according to claim 2, wherein
- said high melting point metal is selected from the group consisting of molybdenum, titanium, tungsten, tantalum and chromium, or an alloy thereof.

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